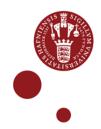
# Lattice Geometry Dependence and Independence: Important Applications of a Simple Law



Steven H. Simon and Mark S. Rudner, Phys. Rev. B **102**, 165148, 2020







### **Tight Binding Models**

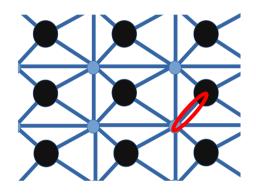
$$H = \sum_{i,j} t_{ij} \, c_i^\dagger c_j$$

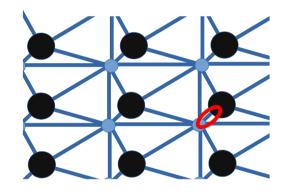
Eigenenergies:  $\epsilon_{lpha}$ 

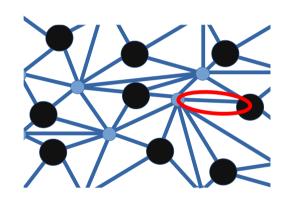
Geometry Independent

Eigenfunctions:  $|\alpha\rangle = \sum_i \psi_i^{(\alpha)} |i\rangle$ 

We have still not specified any geometry! = "real space embedding"







Two ordered and one disordered geometry: Can all share the same H

### **Geometry Independent:**

Eigenenergies, Eigenfunctions

Current along a bond i to j

$$j_{ij}^{(\alpha)} = \frac{-i}{2} \left( t_{ij} \psi_i^{(\alpha)*} \psi_j^{(\alpha)} - h.c. \right)$$

### **Geometry Dependent:**

Charge distribution of an eigenstate

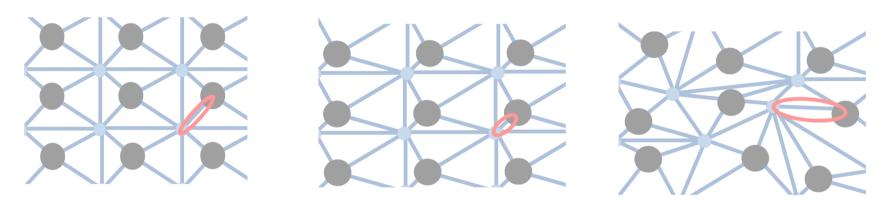
$$q_{\alpha}(\mathbf{r}) = \sum_{i} \delta(\mathbf{r} - \mathbf{r_i}) |\psi_i^{(\alpha)}|^2$$

### SUMMARY OF TALK

Crucial to keep track of which quantities are geometry independent and which are geometry dependent!

Analogous to gauge invariance, quantities which should be geometry indep must behave this way in any calculation.

*Many* "established" results in the literature fail this test!



Two ordered and one disordered geometry: Can all share the same H

### **Geometry Independent:**

Eigenenergies, Eigenfunctions

Current along a bond i to j

$$j_{ij}^{(\alpha)} = \frac{-i}{2} \left( t_{ij} \psi_i^{(\alpha)*} \psi_j^{(\alpha)} - h.c. \right)$$

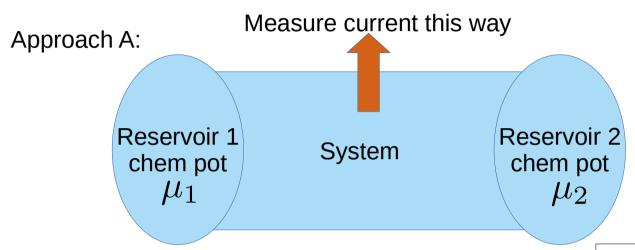
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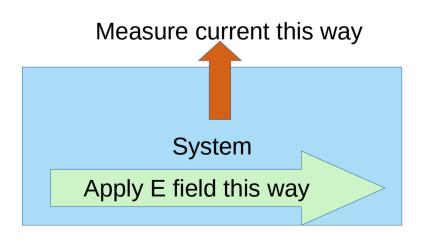
$$q_{\alpha}(\mathbf{r}) = \sum_{i} \delta(\mathbf{r} - \mathbf{r_i}) |\psi_i^{(\alpha)}|^2$$

## Example 1: Hall Response

Apply a bias in x-direction, measure current in y-direction



Approach B:



These look similar .... but ... are entirely different

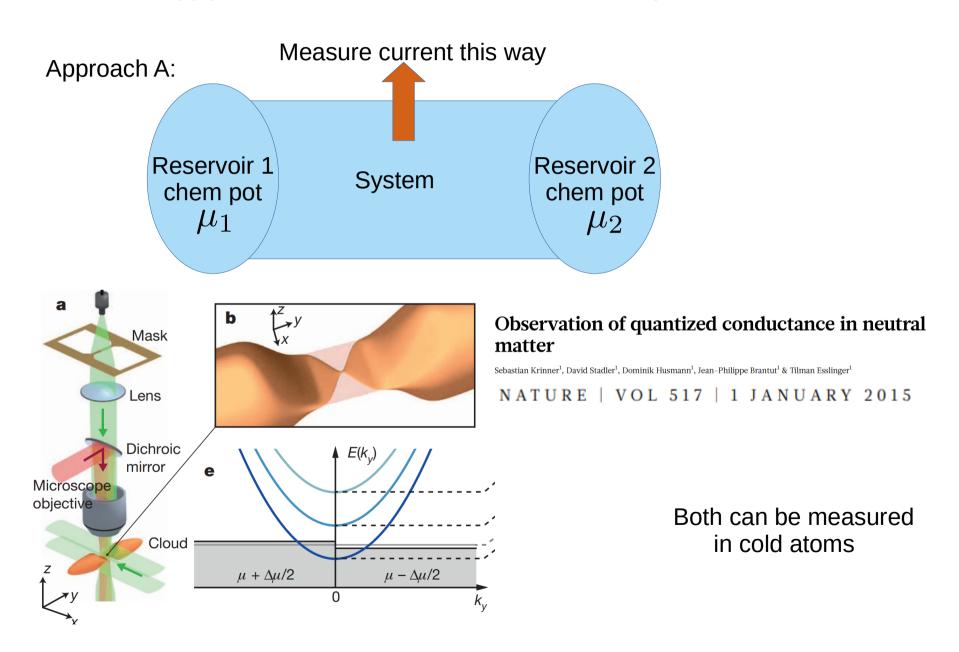
A is geometry independent B is geometry dependent

They cannot act the same!

Both can be measured in cold atoms

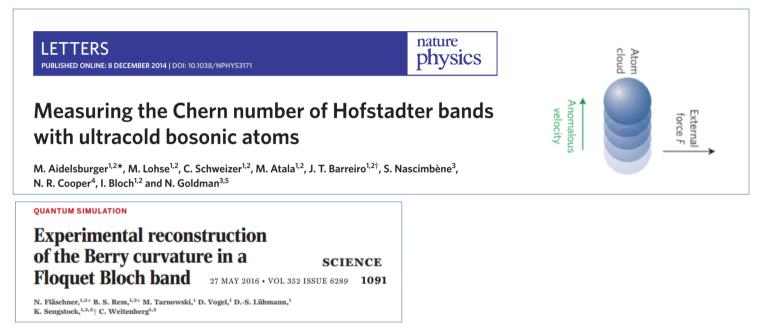
## Example 1: Hall Response

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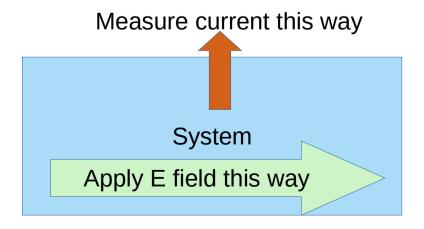


## Example 1: Hall Response

Apply a bias in x-direction, measure current in y-direction

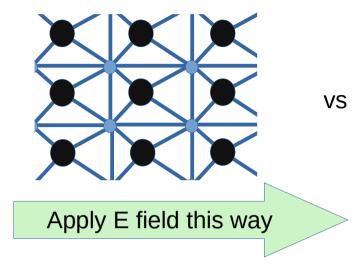


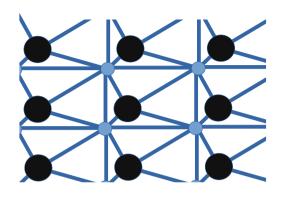
#### Approach B:



Both can be measured in cold atoms

### Approach B:



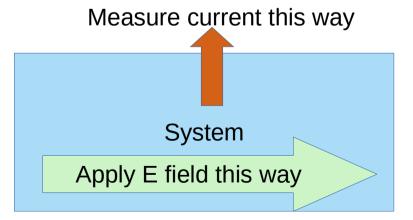


$$\mathbf{E}(\mathbf{r}) = \nabla \phi(\mathbf{r})$$

E may be uniform, but  $\phi$  is not

$$H = \sum_{ij} t_{ij} c_i^{\dagger} c_j + \sum_i \phi(\mathbf{r}_i) c_i^{\dagger} c_i$$

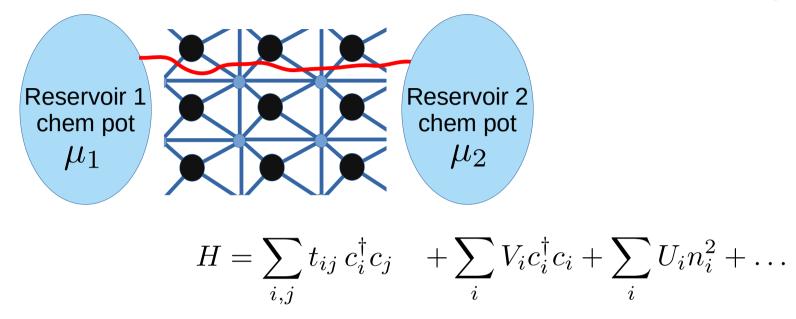
### Approach B:



Explicit geometry dependence

### Approach A:

### measure current crossing red line

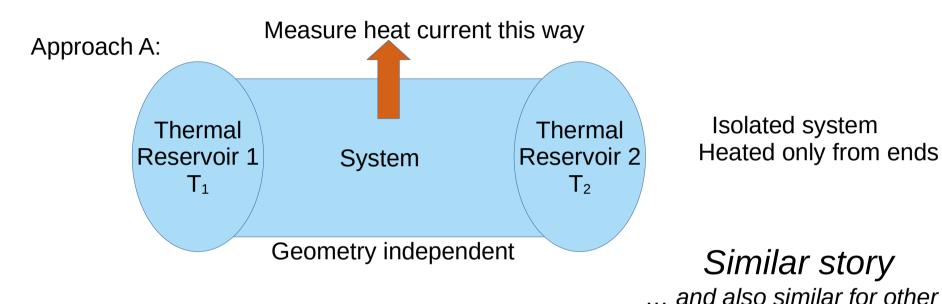


Nowhere do we need to specify the position of any orbitals!

Hall current must be geometry indep!

## Example 1a: Thermal Hall Response (Righi-Leduc Effect)

Apply thermal bias in x-direction, measure heat current in y-direction



Approach B:

System

Apply  $\nabla T$  this way

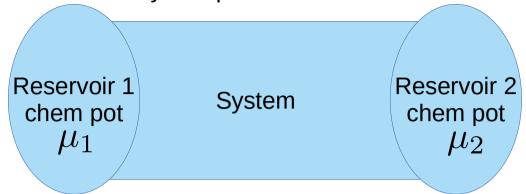
Geometry dependent

Coupling to (ex)
Phonon Heat Bath
everywhere

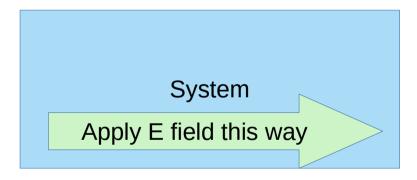
transport coefficients too

(Back to regular Hall)

Approach A: Geometry Independent



Approach B: Geometry Dependent



But could there be a conspiracy?... could (B) end up being unexpectedly geometry indep?

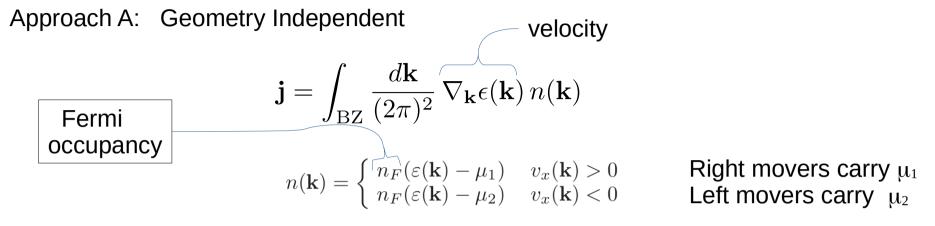
Q&A

## You're Living in the Golden Age of Conspiracy Theories

How the coronavirus pandemic primed America for a new pandemic of misinformation.

Periodic crystal / no disorder / no interaction / 2D / Remove edges:

Calculations can be done exactly



Approach B: Geometry Dependent (Kubo Formula [strictly ω to 0 limit])

$$\mathbf{j}_{Hall} = e\mathbf{E} \times \hat{z} \int_{\mathrm{BZ}} \frac{d\mathbf{k}}{(2\pi)^2} \Omega(\mathbf{k}) n(\mathbf{k})$$
 Berry Curvature

But could there be a conspiracy?... could (B) end up being unexpectedly geometry indep?

Q&A

## You're Living in the Golden Age of Conspiracy Theories

### Detour: What is Berry Curvature?

Berry phase effects on electronic properties Xiao, Chang, Niu RMP 82. 1959. 2010

$$\dot{\mathbf{r}} = \nabla_{\mathbf{k}} \epsilon(\mathbf{k}) - \dot{\mathbf{k}} \times \mathbf{\Omega}(\mathbf{k})$$

$$\dot{\mathbf{k}} = -e\mathbf{E} - e\dot{\mathbf{r}} \times \mathbf{B}$$



$$H = \sum_{i,j} t_{ij} c_i^{\dagger} c_j$$

B, E must be small – large B put into band structure WLOG we drop B

Filled Bloch band (2D):

$$\mathbf{j} = \int_{\mathrm{BZ}} \frac{d\mathbf{k}}{(2\pi)^2} \, \dot{\mathbf{r}}_{\mathbf{k}} = e\mathbf{E} \times \hat{z} \int_{\mathrm{BZ}} \frac{d\mathbf{k}}{(2\pi)^2} \Omega(\mathbf{k})$$

Chern Number (integer) = quantized Hall conduction of filled band ("Chern-Insulator")

#### **Gauss-Bonnet Theorem**

$$\frac{1}{2\pi} \int_{M} K dA = \chi(M)$$





#### Quantized Hall Conductance in a Two-Dimensional Periodic Potential

D. J. Thouless, M. Kohmoto, A. P. Nightingale, and M. den Nijs Department of Physics, University of Washington, Seattle, Washington (Received 30 April 1982)

#### Landau Level:

$$\epsilon(\mathbf{k}) = \text{constant}$$

$$\Omega(\mathbf{k}) = \text{constant}$$

### Calculating Berry Curvature?

Bloch function Periodicity of unit cell

Bloch's theorem:

Geometry indep

$$|\psi(\mathbf{k})\rangle = \sum_{\mathbf{R},\alpha} e^{i\mathbf{k}\cdot\mathbf{R}} \psi_{\alpha}(\mathbf{k}) |\alpha,\mathbf{R}\rangle = e^{i\mathbf{k}\cdot\hat{\mathbf{r}}} |u(\mathbf{k})\rangle$$
Unit cell reference point Orbital within unit cell

$$|u(\mathbf{k})
angle = \sum_{\mathbf{R}, \alpha} u_{lpha}(\mathbf{k}) |lpha, \mathbf{R}
angle$$
 Only geom dep part 
$$u_{lpha}(\mathbf{k}) = e^{-i\mathbf{k}\cdot\mathbf{x}_{lpha}} \psi_{lpha}(\mathbf{k})$$

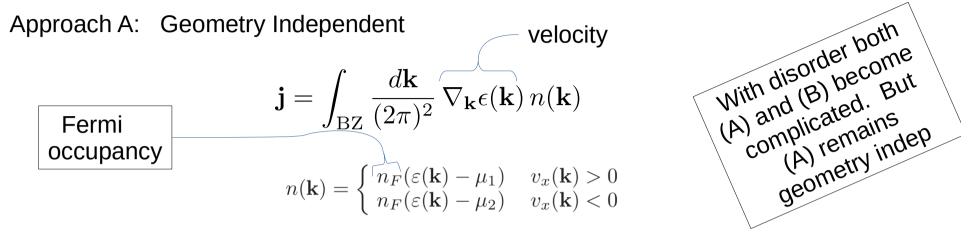
$$\mathbf{A}(\mathbf{k}) = i \langle u(\mathbf{k}) | \nabla_{\mathbf{k}} | u(\mathbf{k}) \rangle$$
 Berry Connection  $\Omega(\mathbf{k}) = \nabla_{\mathbf{k}} \times \mathbf{A}(\mathbf{k})$ 

$$\mathbf{x}_{\alpha} \to \mathbf{x}_{\alpha} + \delta \mathbf{x}_{\alpha}$$

$$\Omega(\mathbf{k}) \to \Omega(\mathbf{k}) + \nabla_{\mathbf{k}} \times \underbrace{(\delta \mathbf{x}_{\alpha} |u_{\alpha}(\mathbf{k})|^{2})}_{\langle \delta \mathbf{x} \rangle_{\mathbf{k}}}$$

$$C = \int_{\rm BZ} \frac{d{\bf k}}{(2\pi)^2} \Omega({\bf k})$$
 unchanged

Periodic crystal / no disorder / 2D / Remove edges: Calculations can be done exactly



Approach B: Geometry Dependent (Kubo Formula [strictly  $\omega$  to 0 limit])

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$$\mathbf{x}_{\alpha} \to \mathbf{x}_{\alpha} + \delta \mathbf{x}_{\alpha}$$
$$\Omega(\mathbf{k}) \to \Omega(\mathbf{k}) + \nabla_{\mathbf{k}} \times \langle \delta \mathbf{x} \rangle_{\mathbf{k}}$$

But could there be a conspiracy?... could (B) end up being unexpectedly geometry indep?

You're Living in the Golden Age of Conspiracy Theories

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## What about experiments in solid state?

(1) Electrons are charged, so *typically* one cannot apply chemical potential difference without electric field (although it is not impossible, at least in 2D)

*Typically,* one measures geometry dependent response.

(2) In spin systems with thermal transport, if the phonons decouple at low T, one *will* have geometry independent physics that violates Kubo!

## Example 2: Fractional Chern Insulators and The Geometric Stability Conjecture

$$\mathbf{j} = e\mathbf{E} \times \hat{z} \int_{\mathrm{BZ}} \frac{d\mathbf{k}}{(2\pi)^2} \Omega(\mathbf{k})$$

Chern Number (integer) = quantized Hall conduction of filled band ("Chern-Insulator")

Landau Level:	More Generally	
$\epsilon(\mathbf{k}) = \text{constant}$	$\epsilon(\mathbf{k})$	Arbitrary
$\Omega(\mathbf{k}) = \text{constant}$	$\Omega({f k})$	Arbitrary subject to integral being an integer

What happens with a partially filled band?

With no/weak interactions: Fermi sea fills lowest  $\epsilon(\mathbf{k})$  With strong interactions: *might* form fractional quantum Hall state "Fractional Chern Insulator"

How do we design a hopping/interaction model to get FQHE

## Example 2: Fractional Chern Insulators and The Geometric Stability Conjecture

FQHE is favored by band structures that "look" like Landau levels



 $\Omega(\mathbf{k})$  should be constant in the Brillouin zone

Many authors (but in most detail by Jackson, Moller, Roy, Nat Comm 2015) Observe correlation between size of FQH gaps and flatness of  $\Omega(\mathbf{k})$ 

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Observe correlation between size of FQH gaps and flatness of  $\Omega(\mathbf{k})$ 

#### This statement can't be correct!

Every example studied used a particularly symmetric geometry of orbitals that happened to maximized flatness of  $\Omega$  given the particular hopping/interaction model

Counter Example: Boson FQHE

$$H = \sum_{i,j} t_{ij} c_i^{\dagger} c_j + \sum_i U n_i^2$$

Geometry Independent Hamiltonian: FQH gaps indep of orbital positions

But  $\Omega(\mathbf{k})$  changes with orbital positions!

### Example 2: Fractional Chern Insulators and

## The *Modified* Geometric Stability Conjecture

For each hopping/interaction model, one should first vary over geometry (ie., orbital positions) before measuring flatness of  $\Omega(\mathbf{k})$ 

Conjecture: correlation between FQH gaps and this flatness of  $\Omega(\mathbf{k})$  (given fixed [flat] dispersion)

Observe correlation between size of FQH gaps and flatness of  $\Omega(\mathbf{k})$ 

Every example studied used a particularly symmetric geometry of orbitals that happened to maximized flatness of  $\Omega$  given the particular hopping/interaction model

Counter Example: Boson FQHE 
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Geometry Independent Hamiltonian: FQH gaps indep of orbital positions  ${\rm But} \ \ \Omega({\bf k}) \ {\rm changes} \ {\rm with} \ {\rm orbital} \ {\rm positions!}$ 

## Summary

Some quantities are geometry independent...

... others are geometry dependent

One cannot make geometry independent statements about geometry independent quantities and vice versa

Some objects (like Hall response) can be either geometry dependent or geometry independent depending on "details" of how they are probed.

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